

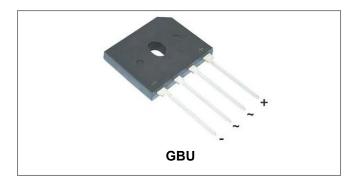
GBU15005 THRU GBU1510

Technical Data Data Sheet N1802, Rev. A

RoHS 🗭

GBU15005 THRU GBU1510

Single-Phase 15.0A Glass Passivated Bridge Rectifier

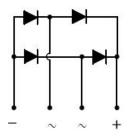


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Features

- Glass passivated die construction
- Low forward voltage drop
- High current capability
- High surge current capability
- Plastic material-UL flammability 94V-0
- This is a Pb Free Device
- All SMC parts are traceable to the wafer lot
- Additional testing can be offered upon request

Circuit Diagram



Mechanical Data

- Case: GBU, Molded plastic
- Terminals: Plated leads solderable per MIL-STD-202, Method 208
- Polarity: as marked on case
- Mounting Position: Any
- Lead Free: For RoHS / Lead Free Version

Maximum Ratings:@T_A=25°C unless otherwise specified

Single Phase, half wave, 60Hz, resistive or inductive load. For capacitive load, derate current by 20%.

Type Number	Symbol	GBU 15005	GBU 1501	GBU 1502	GBU 1504	GBU 1506	GBU 1508	GBU 1510	Units
Peak Repetitive Reverse Voltage Working Peak Reverse Voltage DC Blocking Voltage	V _{RRM} V _{RWM} V _{DC}	50	100	200	400	600	800	1000	V
RMS Reverse Voltage	V _{RMS}	35	70	140	280	420	560	700	V
Average forward rectified output current (Note 1) $@T_A = 40^{\circ}C$	lo				15				A
Non-Repetitive Peak Forward Surge Current 8.3ms Single half sine-wave superimposed on rated load (JEDEC Method)	Ifsm				200				А

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Electrical Characteristics:@T_A=25°C unless otherwise specified

Type Number	Symbol	GBU 15005	GBU 1501	GBU 1502	GBU 1504	GBU 1506	GBU 1508	GBU 1510	Units
Forward Voltage (per element) @I _F =7.5A @I _F =15A	VF				1.0 1.1				V
Peak Reverse Current $@T_A = 25^{\circ}C$ At Rated DC Blocking Voltage $@T_A = 125^{\circ}C$	I _{RM}				5.0 500				μA
Typical Junction Capacitance(per leg) (Note 2)	CJ				70				pF

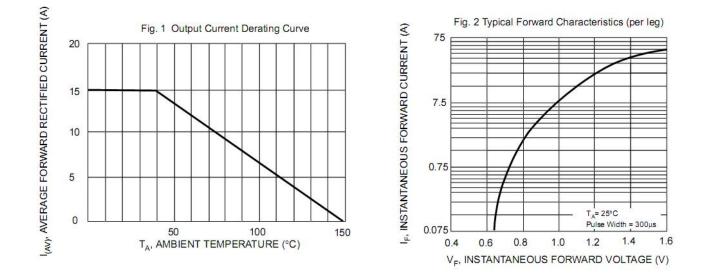
* Pulse width < 300 μ s, duty cycle < 2%

Thermal-Mechanical Specifications:@T_A=25°C unless otherwise specified

Type Number	Symbol	GBU 15005	GBU 1501	GBU 1502	GBU 1504	GBU 1506	GBU 1508	GBU 1510	Units
rpical Thermal Resistance (per leg) ReJL 25 ReJL 2.2			°C/W						
Operating and Storage Temperature Range T				-58	5 to +150)			°C

Note: 1. Mounted on glass epoxy PC board with 1.3mm² solder pad. 2. Measured at 1.0 MHz and applied reverse voltage of 4.0V D.C.

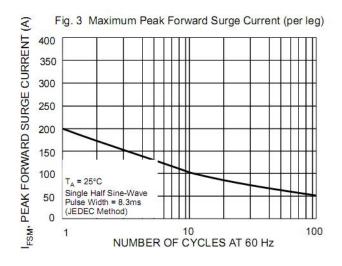
Ratings and Characteristics Curves

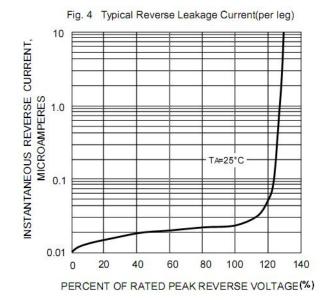






Pb RoHS



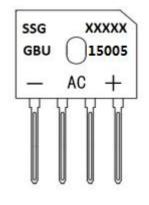


Ordering Information

Device	Package	Plating	Shipping
GBU25005 THRU GBU2510	GBU (Pb-Free)	Pure Sn	20pcs / tube

For information on tape and reel specifications, including part orientation and tape sizes, please refer to our tape and reel packaging specification.

Marking Diagram



Where	XXXXX	İS	YYWWL

SSG	= SSG
YY	= Year
WW	= Week
L	= Lot Number
GBU15005	= Type Number

Cautions: Molding resin Epoxy resin UL:94V-0

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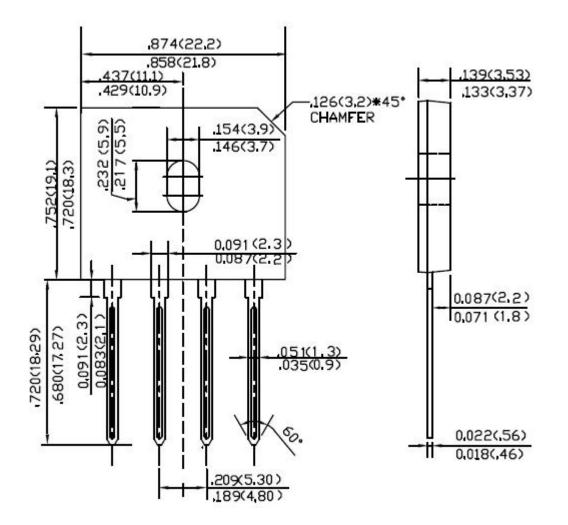
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Mechanical Dimensions GBU (Inches/Millimeters)









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